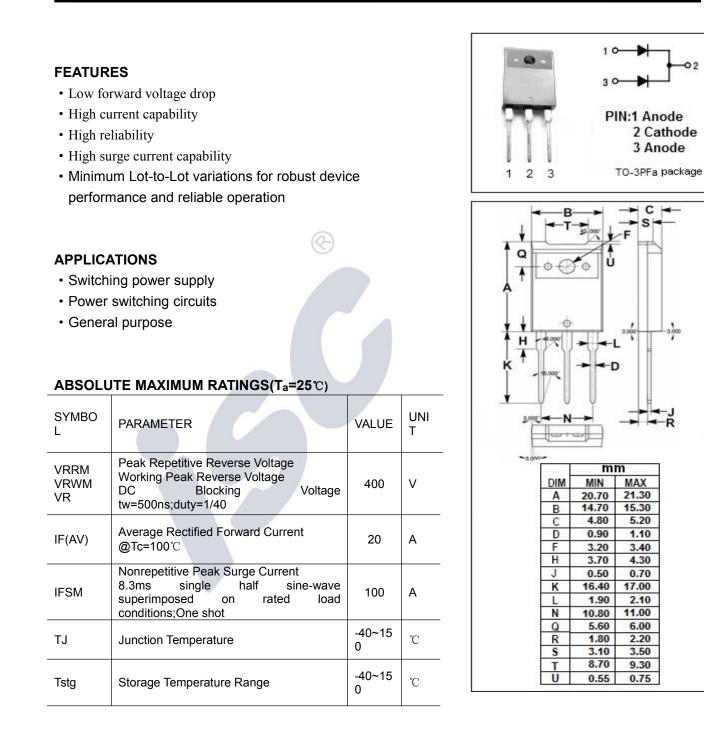


INCHANGE SEMICONDUCTOR

FMD-4206S

02





INCHANGE SEMICONDUCTOR

Ultra fast Rectifier

FMD-4206S

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	2	°C/W

ELECTRICAL CHARACTERISTICS(Ta=25°C) (Pulse Test: Pulse Width=300 µ s,Duty Cycle≤2%)

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
VF	Maximum Instantaneous Forward Voltage	IF=10A	1.4	V
IR	Maximum Instantaneous Reverse Current	VR= V _{RWM;}	20	μA
trr	Maximum Reverse Recovery Time	IF =0.5A;90% Recovery point	30	ns

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